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2SA2016-TD-Е

Data Sheet

Transistors Bipolar - BJT BIP PNP 7A 50V TRANSISTOR PNP

Manufacturers	ON Semiconductor, LLC
Package/Case	SOT-89-3
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for 2SA2016-TD-E or Email to us: sales@ovaga.com We will contact you in 12 hours.	REO
	<u>RFQ</u>

General Description

2SA2016 is a Bipolar Transistor, -50V, -7A, Low VCE(sat), (PNP)NPN Single PCP for DC-DC Converter Applications.

Features

Adoption of FBET and MBIT processes

Large current capacity

Low collector-to-emitter saturation voltage

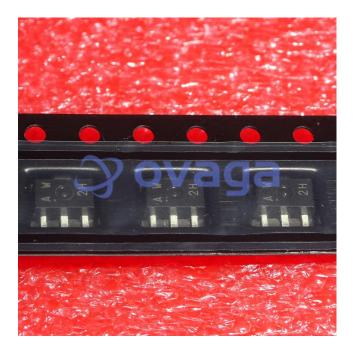
High-speed switching

Ultrasmall package facilitales miniaturization in end products

High allowable power dissipation

Application

ONSEMI



Related Products



2SC4027S-TL-E ON Semiconductor, LLC TO-252



2SC4135T-E ON Semiconductor, LLC





<u>2SD1815S-TL-E</u>

ON Semiconductor, LLC TO-252



2SC3648S-TD-E

ON Semiconductor, LLC SOT-89









2SC5964-TD-E ON Semiconductor, LLC SOT-89

<u>2SA2125-TD-Е</u>

<u>2SC5707-Е</u>

2SC6097-TL-E

TO-251

SC-63

ON Semiconductor, LLC

ON Semiconductor, LLC

ON Semiconductor, LLC SOT-89

